

EAST: [10605010:CMOS TFT parallel and offset.wsp:1]

FileViewEditToolsWindowHelp

L21: (1148720) (perpendicular\$2 orthogonal\$3)

L22: (3134) 21 near 9 10

L23: (5005888) 13 16

L24: (5006008) 23 14

L25: (174121) 24 near 12 21

L26: (240008) 13 near 3 (10) 16 14

L27: (1883) 26 with 21

L28: (8) 27 and 9

L29: (588) (257/87,89) CCLS

L30: (2278) (257/59,72) CCLS

L32: (2778) 29 30

L33: (44) 27 and 32

L31: (63) 28 and 30

L34: (61164) (SRAM static adj 3 memory static adj RAM)

L35: (1429) 34 with 3

L36: (34) 27 and 35

L37: (2487147) parallel "same" adj direction

L38: (11875) 28 with 37

L39: (742) 38 same 6

L41: (154257) lcd

L42: (14) 39 and 41

L40: (21) 38 and 9

L43: (580634) offset

L44: (395) 17 with 43

L45: (181) 3 same 44

Failed

Cancel

BrowseQueueClear

DBsUSPAT:US POPUB:EPO:JPO:DERWENT:IDM:TDB

Default operator:OR

Plurals

Highlight all hit terms initially

J same 44

Sept 2004

Build here

Build term

Build map

Build

Build

	U	F	Investor	Document#	Issue	P	Title	Current	Current	XR	Retrieval	S	C	P				Image	Doc	P
1			Zhang, Hongy	US 2003020	20031:2		Semiconductor display devices and applicati	257/59	257/E21.70			R	F	F	F	F	F	US 200302		
2			So, Woo You	US 2002012	20020:1		Method of manufacturing CMOS thin film tra	438/373	257/E21.70			R	F	F	F	F	F	US 200201		
3			So, Woo You	US 8753235	20040:1		Method of manufacturing CMOS thin film tra	438/373	438/278			R	F	F	F	F	F	US 875323		
4			Zhang, Hongy	US 6614052	20030:2		Semiconductor display devices and applicati	257/59	257/350			R	F	F	F	F	F	US 661405		
5			Ishiguro, Hide	US 6306683	20011:2		Method of manufacturing semiconductor dev	438/148	257/E21.41			R	F	F	F	F	F	US 630668		
6			Kobayashi, K	US 6148930	20001:2		Method of fabricating an active-matrix liquid	438/154	257/E21.70			R	F	F	F	F	F	US 614893		
7			Zhang, Hongy	US 5848107	18990:3		Semiconductor device and method of fabrica	257/347	257/346			R	F	F	F	F	F	US 584810		
8			Maegawa, S	US 5821585	19981:2		Thin film transistor and manufacturing meth	257/347	257/348			R	F	F	F	F	F	US 582158		
9			Kobayashi, K	US 5767930	19980:2		Active-matrix liquid crystal display and fabri	349/42	257/408			R	F	F	F	F	F	US 576793		
10			Koyama, Jun	US 5764206	18980:1		Drive circuit and method for designing the se	345/80	257/58			R	F	F	F	F	F	US 576420		

Inc

Details

Build

Ready

3/10/04